

MBRF3040CT THRU MBRF30200CT

SCHOTTKY BARRIER RECTIFIERS

Reverse Voltage 40 to 200 Volts Forward Current 30 Amperes

0.112(2.85) 0.100(2.55) 0.406(10.3) 0.189(4.8) 0.272(6.9) 0.248(6.3) 0.381(9.7) 0.165(4.2) @0.134(3.4) 0.130(3.3) Ø0.118(3.0) 0.114(2.9) 0.606(15.4) 0.583(14.8) 0.114(2.9) 0.543(13.8) 0.512(13.0) 0.055(1.4) 0.098(2.5) 0.177(4.5) 0.137(3.5) 0.039(1.0) 0.055(1.4) 0.039(1.0) 0.028(0.7) 0.019(0.5) 3 0.027(0.67) 0.100(2.55) 0.100(2.55) 0.022(0.57) 0 AC D AC 3-Unit: inch(mm)

ITO-220AB

FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-O.
 Flame Retardant Epoxy Molding Compound.
- Metal silicon junction, majority carrier conduction
- · Low power loss, high efficiency.
- High surge capacity
- · For use in low voltage, high frequency inverters,
- free wheeling and polarity protection applications
- In compliance with EU RoHS 2002/95/EC directives

MECHANICAL DATA

- · Case:ITO-220AB molded plastic
- Terminals: solder plated, solderable per MIL-STD-750, Method 2026
- · Polarity: As marked.
- Mounting Position: Any
- Weight: 0.055 ounces, 1.5615 grams.

MAXIMUM[®] RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load.

PARAMETER	SYMBOL	MBRF3040CT	MBRF3045CT	MBRF3050CT	MBRF3060CT	MBRF3080CT	MBRF3090CT	MBRF30100CT	MBRF30150CT	MBRF30200CT	UNITS
Maximum Recurrent Peak Reverse Voltage	VRRM	40	45	50	60	80	90	100	150	200	V
Maximum RMS Voltage	VRMS	28	31.5	35	42	56	63	70	105	140	v
Maximum DC Blocking Voltage	VDC	40	45	50	60	80	90	100	150	200	v
Maximum Average Forward Current (see Fig.1)	IF[AV]	30									А
Peak Forward Surge Current:8.3ms single half sine wave superimposed on rated load(JEDEC method)	IFSM	275									А
Maximum Forward Voltage at 10A, per leg	VF	0	.7	0.75		0.8			0	.9	v
Maximum DC Reverse Current Tj=25C at Rated DC Blocking Voltage Tj=125C	IR	0.1 0.05 20 20									mA
Typical Thermal Resistance	RJC	1.4									°C/W
Operating Junction and Storage Temperature Range	TJ,TSTG	-50 to +150 -65 to +175									°C

For capacitive load, derate current by 20%

Note: Both bonding and Chip structure are available.

RATING AND CHARACTERISTIC CURVES



